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Title: Semiconductor Physics of Halide Perovskites

ハライドペロブスカイトはどのような半導体か

Speaker: Prof. Yoshihiko Kanemitsu

ICR, Kyoto Univ. & Riken RAP

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京都大学 化学研究所 特任教授 理化学研究所 光量子工学研究センター 特別顧問

ABX₃-type halide perovskites are receiving much attention as a new class of semiconductor materials from viewpoints of the fundamental physics and applications in optoelectronic devices, because of their excellent properties and ease of fabrication using low-temperature chemical solution processes. Perovskite thin film solar cells show power conversion efficiencies of about 27%, close to the Shockley–Queisser Limit. Perovskite nanocrystal quantum dots exhibit nearly 100% photoluminescence quantum efficiencies and long exciton coherent times. In addition, chiral halide perovskites show unique opto-spintronic properties. Our group at Kyoto Univ. can prepare high-quality samples of single crystals, nanocrystals, and atomically thin layers. This talk discusses the optical, electronic, and thermal properties of halide perovskite semiconductors, summarizing our group's research on the photophysics of halide perovskites.



